

INITIAL RELEASE Final Electrical Specifications LT1638/LT1639

1.2MHz, 0.4V/μs Over-The-Top™ Micropower Rail-to-Rail Input and Output Op Amps June 1998

## FEATURES

- Rail-to-Rail Input and Output
- Low Power: 230µA per Amplifier Max
- Gain Bandwidth Product: 1.2MHz
- Slew Rate: 0.4V/µs
- High Output Current: 25mA Min
- Specified on 3V, 5V and ±15V Supplies
- Reverse Battery Protection to 18V
- No Supply Sequencing Problems
- High Voltage Gain: 1500V/mV
- Single Supply Input Range: -0.4V to 44V
- High CMRR: 98dB
- No Phase Reversal

# **APPLICATIONS**

- Battery- or Solar-Powered Systems Portable Instrumentation Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- Micropower Active Filters
- 4mA to 20mA Transmitters

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# DESCRIPTION

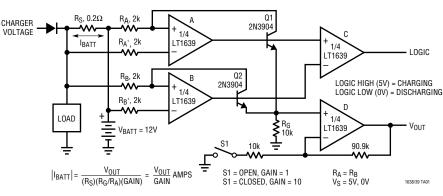
The LT<sup>®</sup>1638 is a low power dual rail-to-rail input and output operational amplifier available in the standard 8-pin PDIP and SO packages as well as the 8-lead MSOP package. The LT1639 is a low power quad rail-to-rail input and output operational amplifier offered on the standard 14-pin PDIP and surface mount packages.

The LT1638/LT1639 op amps operate on all single and split supplies with a total voltage of 2.5V to 44V drawing only 170 $\mu$ A of quiescent current per amplifier. These amplifiers are reverse battery protected and draw no current for reverse supply up to 18V.

The input range of the LT1638/LT1639 includes both supplies, and a unique feature of this device is its capability to operate over the top with either or both of its inputs above V<sup>+</sup>. The inputs handle 44V, both differential and common mode, independent of supply voltage. The input stage incorporates phase reversal protection to prevent false outputs from occurring even when the inputs are 22V below the negative supply. Protective resistors are included in the input leads so that current does not become excessive when the inputs are forced below the negative supply. The LT1638/LT1639 can drive loads up to 25mA and still maintain rail-to-rail capability. The op amps are unity-gain stable and drive all capacitive loads up to 1000pF when optional output compensation is used.

# TYPICAL APPLICATION







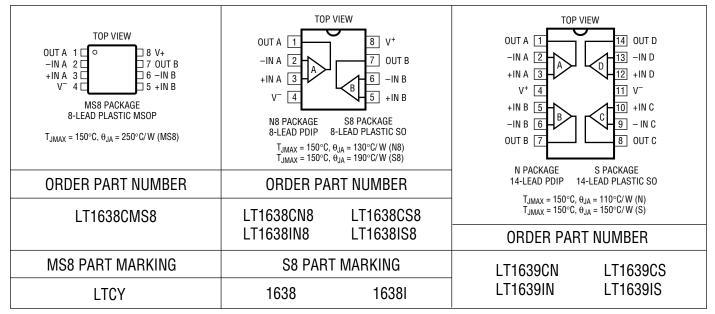
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# **ABSOLUTE MAXIMUM RATINGS**

Total Supply Voltage (V <sup>+</sup> to V <sup>-</sup> )	44V
Input Differential Voltage	44V
Input Current	±25mA
Output Short-Circuit Duration (Note 1)	Continuous
Operating Temperature Range	–40°C to 85°C

Specified Temperature Range (Note 2)	40°C to 85°C
Junction Temperature	150°C
Storage Temperature Range6	5°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

# PACKAGE/ORDER INFORMATION



Consult factory for Military grade parts.

# **ELECTRICAL CHARACTERISTICS**

 $V_S$  = 3V, 0V;  $V_S$  = 5V, 0V;  $V_{CM}$  =  $V_{OUT}$  = half supply,  $T_A$  = 25°C, unless otherwise noted. (Note 2)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V <sub>OS</sub>	Input Offset Voltage	LT1638 N, S Packages			200	600	μV
		$0^{\circ}C \le T_A \le 70^{\circ}C$	•			850	μV
		$-40^{\circ}C \le T_A \le 85^{\circ}C$	•			950	μV
		LT1639 N, S Packages			300	700	μV
		$0^{\circ}C \le T_A \le 70^{\circ}C$	•			950	μV
		$-40^{\circ}C \le T_A \le 85^{\circ}C$	•			1050	μV
		LT1638C MS8 Package			350	900	μV
		$0^{\circ}C \le T_A \le 70^{\circ}C$	•			1150	μV
		$-40^{\circ}C \le T_A \le 85^{\circ}C$	•			1250	μV
	Input Offset Voltage Drift	LT1638/LT1639 N, S Packages	•		2	6	μV/°C
	(Note 6)	LT1638CMS8	•		2.5	7	μV/°C
I <sub>OS</sub>	Input Offset Current		•		1	6	nA
		$V_{CM} = 44V$ (Note 3)	•			2.5	μA



# **ELECTRICAL CHARACTERISTICS**

 $V_S$  = 3V, 0V;  $V_S$  = 5V, 0V;  $V_{CM}$  =  $V_{OUT}$  = half supply,  $T_A$  = 25°C, unless otherwise noted. (Note 2)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
IB	Input Bias Current	V <sub>CM</sub> = 44V (Note 3) V <sub>S</sub> = 0V	•		20 8 0.1	50 30	nA μA nA
	Input Noise Voltage	0.1Hz to 10Hz			1		μV <sub>P-P</sub>
e <sub>n</sub>	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz
in	Input Noise Current Density	f = 1kHz			0.3		pA/√Hz
R <sub>IN</sub>	Input Resistance	Differential Common Mode, V <sub>CM</sub> = 0V to 44V		1 1.4	2.5 5.5		ΜΩ ΜΩ
CIN	Input Capacitance				5		pF
	Input Voltage Range		•	0		44	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0V$ to $V_{CC} - 1V$ $V_{CM} = 0V$ to 44V (Note 7)	•	88 80	98 88		dB dB
A <sub>VOL</sub>	Large-Signal Voltage Gain	$ \begin{split} &V_S = 3V,  V_0 = 500 mV \text{ to } 2.5V,  R_L = 10k \\ &0^\circ C \leq T_A \leq 70^\circ C \\ &-40^\circ C \leq T_A \leq 85^\circ C \end{split} $	•	200 133 100	1500		V/mV V/mV V/mV
			•	400 250 200	1500		V/mV V/mV V/mV
V <sub>OL</sub>	Output Voltage Swing Low	V <sub>S</sub> = 3V, No Load V <sub>S</sub> = 3V, I <sub>SINK</sub> = 5mA	•		3 250	8 450	mV mV
		V <sub>S</sub> = 5V, No Load V <sub>S</sub> = 5V, I <sub>SINK</sub> = 10mA	•		3 500	8 700	mV mV
V <sub>OH</sub>	Output Voltage Swing High	V <sub>S</sub> = 3V, No Load V <sub>S</sub> = 3V, I <sub>SOURCE</sub> = 5mA	•	2.94 2.25	2.98 2.40		V V
		V <sub>S</sub> = 5V, No Load V <sub>S</sub> = 5V, I <sub>SOURCE</sub> = 10mA	•	4.94 3.8	4.98 4.0		V V
I <sub>SC</sub>	Short-Circuit Current (Note 1)	$V_S = 3V$ , Short to GND $V_S = 3V$ , Short to $V_{CC}$		10 15	15 25		mA mA
		V <sub>S</sub> = 5V, Short to GND V <sub>S</sub> = 5V, Short to V <sub>CC</sub>		15 15	20 25		mA mA
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$	•	90	100		dB
	Reverse Supply Voltage	$I_{\rm S} = -100 \mu A$ per Amplifier	•	18	27		V
	Minimum Operating Supply Voltage		•		2.4	2.7	V
ls	Supply Current per Amplifier (Note 4)		•		170	230 275	μΑ μΑ
GBW	Gain Bandwidth Product (Note 3)		•	650 550 500	1075		kHz kHz kHz
SR	Slew Rate (Note 5)	$\begin{array}{l} A_V = -1, \ R_L = \infty \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array}$	•	0.210 0.185 0.170	0.38		V/μs V/μs V/μs

# **ELECTRICAL CHARACTERISTICS**

 $V_S = \pm 15V$ ,  $V_{CM} = 0V$ ,  $V_{OUT} = 0V$ ,  $T_A = 25^{\circ}C$ , unless otherwise noted. (Note 2)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V <sub>OS</sub>	Input Offset Voltage	LT1638 N, S Packages $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		250	800 1000 1100	μV μV μV
		LT1639 N, S Packages $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		350	900 1100 1200	μV μV μV
		LT1638C MS8 Package $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		400	1050 1250 1350	μV μV μV
	Input Offset Voltage Drift (Note 6)	LT1638/LT1639 N, S Packages LT1638CMS8	•		2 2.5	6 7	μV/°C μV/°C
l <sub>os</sub>	Input Offset Current		•		1	6	nA
IB	Input Bias Current		•		20	50	nA
	Input Noise Voltage	0.1Hz to 10Hz			1		μV <sub>P-P</sub>
e <sub>n</sub>	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz
i <sub>n</sub>	Input Noise Current Density	f = 1kHz			0.3		pA/√Hz
R <sub>IN</sub>	Input Resistance	Differential Common Mode, V <sub>CM</sub> = -15V to 14V		1	2.5 500		ΜΩ ΜΩ
CIN	Input Capacitance				4.5		pF
	Input Voltage Range			-15		29	V
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> = -15V to 29V	•	80	88		dB
A <sub>VOL</sub>	Large-Signal Voltage Gain	$V_0 = \pm 14V, R_L = 10k$ $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•	200 125 100	500		V/mV V/mV V/mV
V <sub>OL</sub>	Output Voltage Swing	No Load I <sub>OUT</sub> = ±10mA	•	14.9 13.7	14.95 14.0		V V
I <sub>SC</sub>	Short-Circuit Current (Note 1)	Short to GND $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•	25 20 15	40		mA mA mA
PSRR	Power Supply Rejection Ratio	$V_{S} = \pm 1.5 V$ to $\pm 22 V$		90	100		dB
I <sub>S</sub>	Supply Current per Amplifier		•		205	280 350	μΑ μΑ
GBW	Gain Bandwidth Product		•	750 650 600	1200		kHz kHz kHz
SR	Slew Rate	$ \begin{array}{l} A_V = -1, \ R_L = \infty, \ V_0 = \pm 10V, \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	0.225 0.2 0.18	0.4		V/μs V/μs V/μs

The  $\bullet$  denotes specifications which apply over the full specified temperature range.

**Note 1:** A heat sink may be required to keep the junction temperature below absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted.

**Note 2:** The LT1638C/LT1639C are guaranteed to meet 0°C to 70°C specifications and are designed, characterized and expected to meet the extended temperature limits, but are not tested at -40°C and 85°C. The LT1638I/LT1639I are guaranteed to meet the extended temperature limits.

Note 3:  $V_S$  = 5V limits are guaranteed by correlation to  $V_S$  = 3V and  $V_S$  =  $\pm 15V$  tests.

Note 4:  $V_S$  = 3V limits are guaranteed by correlation to  $V_S$  = 5V and  $V_S$  =  $\pm 15V$  tests.

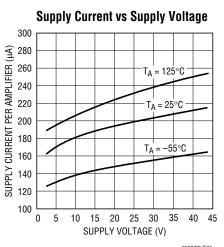
Note 5: Guaranteed by correlation to slew rate at  $V_S$  =  $\pm 15V$  and GBW at  $V_S$  = 3V and  $V_S$  =  $\pm 15V$  tests.

Note 6: This parameter is not 100% tested.

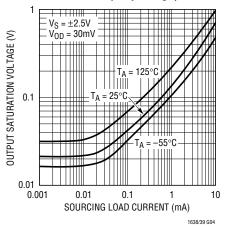
Note 7: The spec implies a typical offset voltage at V<sub>CM</sub> = 44 of 2mV and a maximum offset voltage at V<sub>CM</sub> = 44 of 5mV.



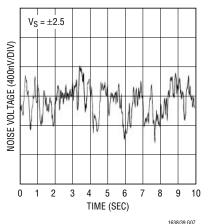
## TYPICAL PERFORMANCE CHARACTERISTICS

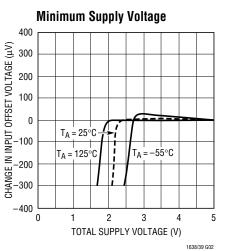


Output Saturation Voltage vs Load Current (Output High)

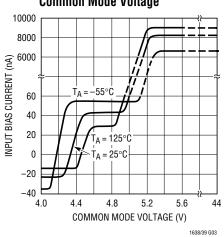


0.1Hz to 10Hz Noise Voltage

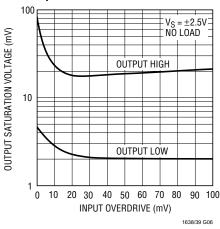




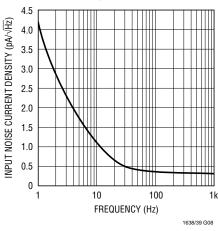
Input Bias Current vs Common Mode Voltage



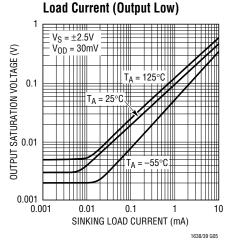
Output Saturation Voltage vs Input Overdrive



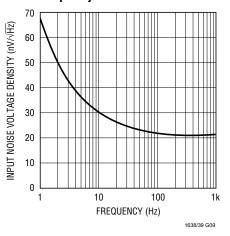
Input Noise Current Density vs Frequency



### 1638/39 GO1 VS Output Saturation Voltage vs

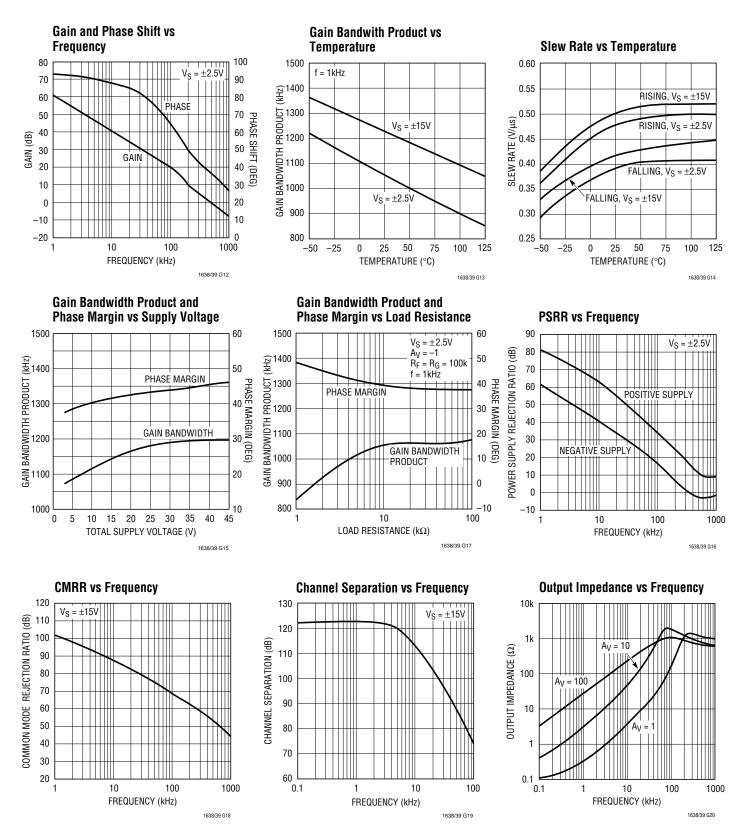


Noise Voltage Density vs Frequency





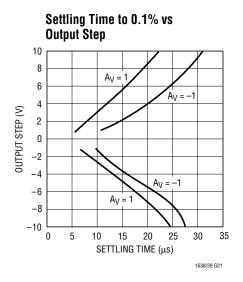
# TYPICAL PERFORMANCE CHARACTERISTICS

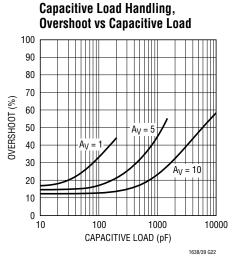


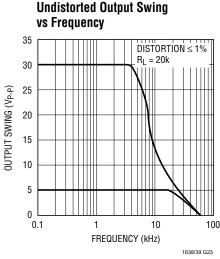


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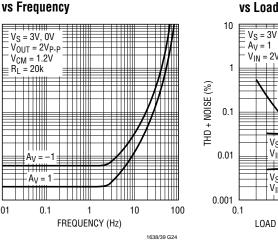
## TYPICAL PERFORMANCE CHARACTERISTICS



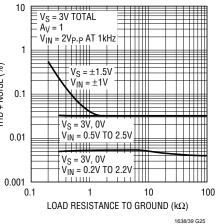




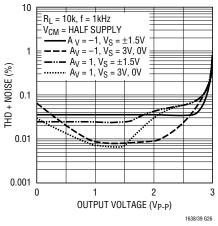
Total Harmonic Distortion + Noise



**Total Harmonic Distortion + Noise** vs Load Resistance



**Total Harmonic Distortion + Noise** vs Output Voltage



**Open-Loop Gain** 

10

1

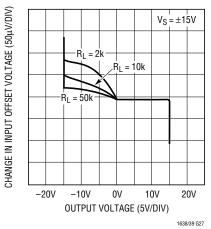
0.1

0.01

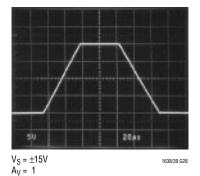
0.001

0.01

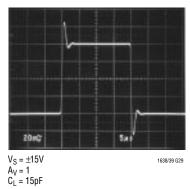
THD + NOISE (%)



#### Large-Signal Response



**Small-Signal Response** 





# **APPLICATIONS INFORMATION**

### Supply Voltage

The positive supply pin of the LT1638/LT1639 should be bypassed with a small capacitor (typically  $0.1\mu$ F) within an inch of the pin. When driving heavy loads an additional  $4.7\mu$ F electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1638/LT1639 are protected against reverse battery voltages up to 18V. In the event a reverse battery condition occurs, the supply current is less than 1nA.

The LT1638/LT1639 can be shut down by removing V<sup>+</sup>. In this condition the input bias current is less than 0.1nA, even if the inputs are 44V above the negative supply.

At temperatures greater than 70°C, when operating the LT1638/LT1639 on total supplies of 10V or more, the supply must not be brought up faster than  $1V/\mu$ s. Increasing the bypass capacitor and/or adding a small resistor in series with the supply will limit the rise time.

### Inputs

The LT1638/LT1639 have two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.8V or more below V<sup>+</sup>, the PNP input stage is active and the input bias current is typically -20nA. When the input common mode voltage is within 0.5V of the positive rail, the NPN stage is operating and the input bias current is typically 40nA. Increases in temperature will cause the voltage at which operation switches from the PNP input stage to the NPN input stage to move towards V<sup>+</sup>. The input offset voltage of the NPN stage is untrimmed and is typically 600 $\mu$ V.

A Schottky diode in the collector of each NPN transistor allow the LT1638/LT1639 to operate over the top, with either or both of its inputs above V<sup>+</sup>. At about 0.3V above V<sup>+</sup> the NPN input transistor is fully saturated and the input bias current is typically  $8\mu$ A at room temperature. The input offset voltage is typically 2mV when operating above V<sup>+</sup>. The LT1638/LT1639 will operate with its inputs 44V above V<sup>-</sup> regardless of V<sup>+</sup>. The inputs are protected against excursions as much as 22V below V<sup>-</sup> by an internal 1k resistor in series with each input and a diode from the input to the negative supply. The input stage of the LT1638/LT1639 incorporates phase reversal protection to prevent the output from phase reversing for inputs up to 22V below V<sup>-</sup>. There are no clamping diodes between the inputs and the maximum differential input voltage is 44V.

### Output

The output of the LT1638/LT1639 can swing within 20mV of the positive rail with no load, and within 3mV of the negative rail with no load. When monitoring voltages within 20mV of the positive rail or within 3mV of the negative rail, gain should be taken to keep the output from clipping. The LT1638/LT1639 are capable of sinking and sourcing over 40mA on  $\pm$ 15V supplies; sourcing current capability is reduced to 20mA at 5V total supplies as noted in the electrical characteristics.

The LT1638/LT1639 are internally compensated to drive at least 200pF of capacitance under any output loading conditions. A  $0.22\mu$ F capacitor in series with a  $150\Omega$  resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 1000pF, at all output currents.

### Distortion

There are two main contributors of distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current and distortion caused by nonlinear common mode rejection. If the op amp is operating inverting there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 0.8V of V<sup>+</sup>), the CMRR is very good, typically 98dB. When the LT1638 switches between input stages there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion, but has no effect on the input stage transition distortion. For lowest distortion the LT1638/LT1639 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and  $(V^+ - 0.8V)$ . See the Typical Performance Characteristics curves.

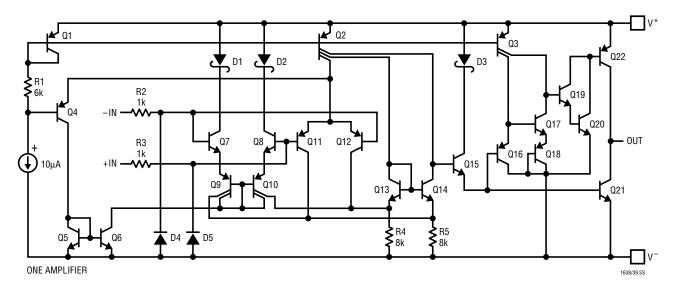


### **APPLICATIONS INFORMATION**

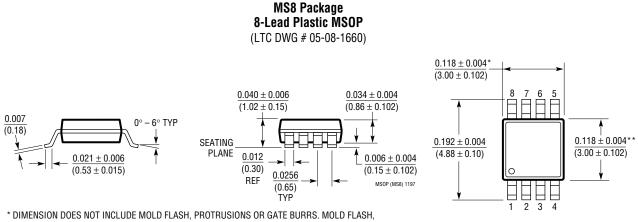
#### Gain

The open-loop gain is almost independent of load when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance curve of Open-Loop Gain for various loads shows the details.





**PACKAGE DESCRIPTION** Dimensions in inches (millimeters) unless otherwise noted.

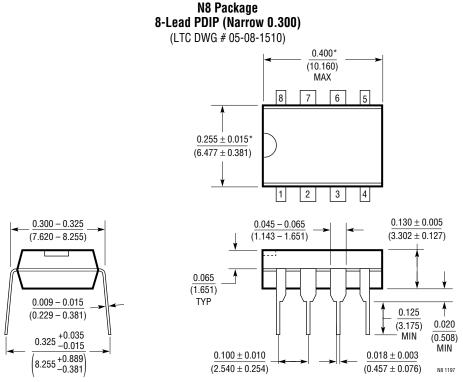


PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.

INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE



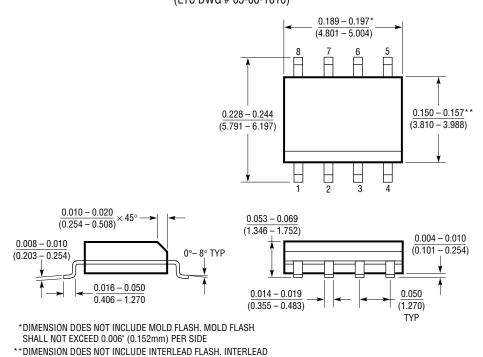
### PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.



\*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

S8 Package 8-Lead Plastic Small Outline (Narrow 0.150) (LTC DWG # 05-08-1610)



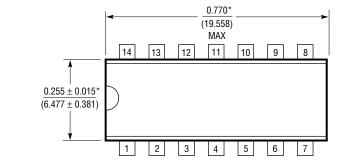
LEAD

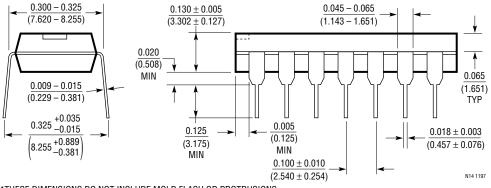


SO8 0996

PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

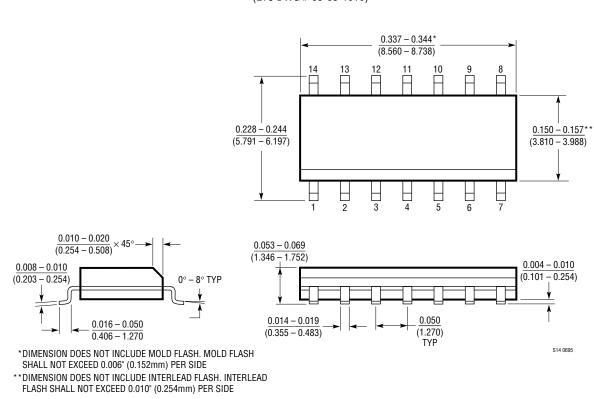
N Package 14-Lead PDIP (Narrow 0.300) (LTC DWG # 05-08-1510)





<sup>\*</sup>THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

## PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.



S Package 14-Lead Plastic Small Outline (Narrow 0.150) (LTC DWG # 05-08-1610)

## **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS
LT1078/LT1079 LT2078/LT2079	Dual/Quad 55µA Max, Single Supply, Precision Op Amps	Input/Output Common Mode Includes Ground, 70 $\mu$ V V <sub>OS(MAX)</sub> and 2.5 $\mu$ V/°C Drift (Max), 200kHz GBW, 0.07V/ $\mu$ s Slew Rate
LT1178/LT1179 LT2178/LT2179	Dual/Quad 17µA Max, Single Supply, Precison Op Amps	Input/Output Common Mode Includes Ground, 70 $\mu$ V V <sub>OS(MAX)</sub> and 4 $\mu$ V/°C Drift (Max), 85kHz GBW, 0.04V/ $\mu$ s Slew Rate
LT1366/LT1367	Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps	475μV V <sub>OS(MAX)</sub> , 500V/mV A <sub>VOL(MIN)</sub> , 400kHz GBW
LT1490/LT1491	Dual/Quad Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: –0.4V to 44V, Micropower 50µA per Amplifier, Rail-to-Rail Input and Output, 200kHz GBW
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	55 $\mu$ A Supply Current, V <sub>CM</sub> Extends 44V above V <sub>EE</sub> , Independent of V <sub>CC</sub> ; MSOP Package, Shutdown Function